

| | Type | L # | Hits | Search Text | DBs | Time Stamp |
|---|------|-----|------|---|--|---------------------|
| 1 | BRS | L1 | 9316 | semiconductor and ((thin adj film adj transistor) or tft) and (gate adj electrode) | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2002/01/26 11:23 |
| 2 | BRS | L2 | 497 | 1 and taper\$3 | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2002/01/26 11:26 |
| 3 | BRS | L3 | 138 | 2 and (1dd or (lightly adj doped adj drain)) | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2002/01/26 11:27 |

| | Comments | Error Definition | Errors |
|---|----------|------------------|--------|
| 1 | | | 0 |
| 2 | | | 0 |
| 3 | | | 0 |